SG3525A

Pulse Width Modulator Control Circuit

The SG3525A pulse width modulator control circuit offers improved performance and lower external parts count when implemented for controlling all types of switching power supplies. The on-chip +5.1 V reference is trimmed to $\pm 1\%$ and the error amplifier has an input common-mode voltage range that includes the reference voltage, thus eliminating the need for external divider resistors. A sync input to the oscillator enables multiple units to be slaved or a single unit to be synchronized to an external system clock. A wide range of deadtime can be programmed by a single resistor connected between the C_T and Discharge pins. This device also features built-in soft-start circuitry, requiring only an external timing capacitor. A shutdown pin controls both the soft-start circuitry and the output stages, providing instantaneous turn off through the PWM latch with pulsed shutdown, as well as soft-start recycle with longer shutdown commands. The under voltage lockout inhibits the outputs and the changing of the soft-start capacitor when V_{CC} is below nominal. The output stages are totem-pole design capable of sinking and sourcing in excess of 200 mA. The output stage of the SG3525A features NOR logic resulting in a low output for an off-state.

Features

- 8.0 V to 35 V Operation
- 5.1 V ± 1.0% Trimmed Reference
- 100 Hz to 400 kHz Oscillator Range
- Separate Oscillator Sync Pin
- Adjustable Deadtime Control
- Input Undervoltage Lockout
- Latching PWM to Prevent Multiple Pulses
- Pulse-by-Pulse Shutdown
- Dual Source/Sink Outputs: ±400 mA Peak
- Pb-Free Packages are Available*



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MARKING DIAGRAMS

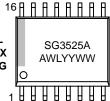


PDIP-16 N SUFFIX CASE 648





SOIC-16L DW SUFFIX CASE 751G



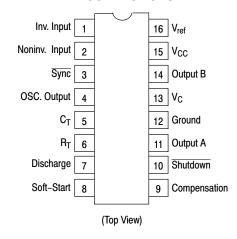
= Assembly Location

WL = Wafer Lot

YY = Year

WW = Work Week

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

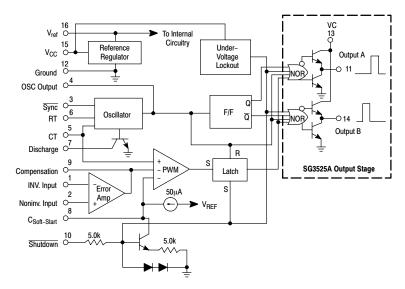


Figure 1. Representative Block Diagram

ORDERING INFORMATION

Device	Package	Shipping [†]
SG3525AN	PDIP-16	25 Units / Rail
SG3525ANG	PDIP-16 (Pb-Free)	25 Units / Rail
SG3525ADW	SOIC-16L	47 Units / Rail
SG3525ADWG	SOIC-16L (Pb-Free)	47 Units / Rail
SG3525ADWR2	SOIC-16L	1000 Tape & Reel
SG3525ADWR2G	SOIC-16L (Pb-Free)	1000 Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage	V _{CC}	+40	Vdc
Collector Supply Voltage	V _C	+40	Vdc
Logic Inputs		-0.3 to +5.5	V
Analog Inputs		–0.3 to V _{CC}	V
Output Current, Source or Sink	Io	±500	mA
Reference Output Current	I _{ref}	50	mA
Oscillator Charging Current		5.0	mA
Power Dissipation $T_A = +25^{\circ}C \text{ (Note 1)}$ $T_C = +25^{\circ}C \text{ (Note 2)}$	P _D	1000 2000	mW
Thermal Resistance, Junction-to-Air	$R_{ hetaJA}$	100	°C/W
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	60	°C/W
Operating Junction Temperature	TJ	+150	°C
Storage Temperature Range	T _{stg}	-55 to +125	°C
Lead Temperature (Soldering, 10 seconds)	T _{Solder}	+300	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1. Derate at 10 mW/°C for ambient temperatures above +50°C.
- 2. Derate at 16 mW/°C for case temperatures above +25°C.

RECOMMENDED OPERATING CONDITIONS

Characteristics	Symbol	Min	Max	Unit
Supply Voltage	V _{CC}	8.0	35	Vdc
Collector Supply Voltage	V _C	4.5	35	Vdc
Output Sink/Source Current (Steady State) (Peak)	Io	0 0	±100 ±400	mA
Reference Load Current	I _{ref}	0	20	mA
Oscillator Frequency Range	f _{osc}	0.1	400	kHz
Oscillator Timing Resistor	R _T	2.0	150	kΩ
Oscillator Timing Capacitor	C _T	0.001	0.2	μF
Deadtime Resistor Range	R _D	0	500	Ω
Operating Ambient Temperature Range	T _A	0	+70	°C

APPLICATION INFORMATION

Shutdown Options (See Block Diagram, page 2)

Since both the compensation and soft–start terminals (Pins 9 and 8) have current source pull–ups, either can readily accept a pull–down signal which only has to sink a maximum of $100~\mu A$ to turn off the outputs. This is subject to the added requirement of discharging whatever external capacitance may be attached to these pins.

An alternate approach is the use of the shutdown circuitry of Pin 10 which has been improved to enhance the available shutdown options. Activating this circuit by applying a positive signal on Pin 10 performs two functions: the PWM

latch is immediately set providing the fastest turn–off signal to the outputs; and a 150 μA current sink begins to discharge the external soft–start capacitor. If the shutdown command is short, the PWM signal is terminated without significant discharge of the soft–start capacitor, thus, allowing, for example, a convenient implementation of pulse–by–pulse current limiting. Holding Pin 10 high for a longer duration, however, will ultimately discharge this external capacitor, recycling slow turn–on upon release.

Pin 10 should not be left floating as noise pickup could conceivably interrupt normal operation.

SG3525A

ELECTRICAL CHARACTERISTICS ($V_{CC} = +20 \text{ Vdc}$, $T_A = T_{low}$ to T_{high} [Note 3], unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
REFERENCE SECTION		•	•	•	
Reference Output Voltage (T _J = +25°C)	V _{ref}	5.00	5.10	5.20	Vdc
Line Regulation (+8.0 V \leq V _{CC} \leq +35 V)	Reg _{line}	_	10	20	mV
Load Regulation (0 mA ≤ I _L ≤ 20 mA)	Reg _{load}	_	20	50	mV
Temperature Stability	$\Delta V_{ref}/\Delta T$	_	20	-	mV
Total Output Variation Includes Line and Load Regulation over Temperature	ΔV_{ref}	4.95	_	5.25	Vdc
Short Circuit Current (V _{ref} = 0 V, T _J = +25°C)	I _{SC}	_	80	100	mA
Output Noise Voltage (10 Hz \leq f \leq 10 kHz, T _J = +25°C)	V _n	_	40	200	μV_{rms}
Long Term Stability (T _J = +125°C) (Note 4)	S	_	20	50	mV/khr
OSCILLATOR SECTION (Note 5, unless otherwise noted.)					
Initial Accuracy (T _J = +25°C)		-	±2.0	±6.0	%
Frequency Stability with Voltage $(+8.0 \text{ V} \leq V_{CC} \leq +35 \text{ V})$	$\frac{\Delta f_{OSC}}{D_{VCC}}$	_	±1.0	±2.0	%
Frequency Stability with Temperature	$\frac{\Delta f_{OSC}}{DT}$	_	±0.3	-	%
Minimum Frequency ($R_T = 150 \text{ k}\Omega, C_T = 0.2 \mu\text{F}$)	f _{min}	_	50	-	Hz
Maximum Frequency ($R_T = 2.0 \text{ k}\Omega$, $C_T = 1.0 \text{ nF}$)	f _{max}	400	_	-	kHz
Current Mirror (I _{RT} = 2.0 mA)		1.7	2.0	2.2	mA
Clock Amplitude		3.0	3.5	-	V
Clock Width $(T_J = +25^{\circ}C)$		0.3	0.5	1.0	μS
Sync Threshold		1.2	2.0	2.8	V
Sync Input Current (Sync Voltage = +3.5 V)		_	1.0	2.5	mA
ERROR AMPLIFIER SECTION (V _{CM} = +5.1 V)		=	=	_	_
Input Offset Voltage	V _{IO}	-	2.0	10	mV
Input Bias Current	I _{IB}	-	1.0	10	μΑ
Input Offset Current	I _{IO}	-	-	1.0	μΑ
DC Open Loop Gain ($R_L \ge 10 \text{ M}\Omega$)	A _{VOL}	60	75	-	dB
Low Level Output Voltage	V _{OL}	_	0.2	0.5	V
High Level Output Voltage	V _{OH}	3.8	5.6	-	V
Common Mode Rejection Ratio (+1.5 V \leq V _{CM} \leq +5.2 V)	CMRR	60	75	-	dB
Power Supply Rejection Ratio (+8.0 V \leq V _{CC} \leq +35 V)	PSRR	50	60	-	dB
PWM COMPARATOR SECTION					
Minimum Duty Cycle	DC _{min}	-	-	0	%
Maximum Duty Cycle	DC _{max}	45	49	_	%
Input Threshold, Zero Duty Cycle (Note 5)	V_{th}	0.6	0.9	_	V
Input Threshold, Maximum Duty Cycle (Note 5)	V_{th}	_	3.3	3.6	V
Input Bias Current	I _{IB}	_	0.05	1.0	μΑ

T_{low} = 0° T_{high} = +70°C
 Since long term stability cannot be measured on each device before shipment, this specification is an engineering estimate of average stability from lot to lot.
 Tested at f_{osc} = 40 kHz (R_T = 3.6 kΩ, C_T = 0.01 μF, R_D = 0 Ω).

SG3525A

ELECTRICAL CHARACTERISTICS (continued)

Characteristics	Symbol	Min	Тур	Max	Unit
SOFT-START SECTION				•	
Soft-Start Current (V _{shutdown} = 0 V)		25	50	80	μΑ
Soft-Start Voltage (V _{shutdown} = 2.0 V)		-	0.4	0.6	V
Shutdown Input Current (V _{shutdown} = 2.5 V)		-	0.4	1.0	mA
OUTPUT DRIVERS (Each Output, V _{CC} = +20 V)	<u>.</u>				
Output Low Level (I _{sink} = 20 mA) (I _{sink} = 100 mA)	V _{OL}	- -	0.2 1.0	0.4 2.0	V
Output High Level (I _{source} = 20 mA) (I _{source} = 100 mA)	Voн	18 17	19 18	_ _	V
Under Voltage Lockout (V8 and V9 = High)	V _{UL}	6.0	7.0	8.0	V
Collector Leakage, V _C = +35 V (Note 6)	I _{C(leak)}	-	_	200	μΑ
Rise Time ($C_L = 1.0 \text{ nF}, T_J = 25^{\circ}\text{C}$)	t _r	-	100	600	ns
Fall Time ($C_L = 1.0 \text{ nF}, T_J = 25^{\circ}\text{C}$)	t _f	-	50	300	ns
Shutdown Delay (V_{DS} = +3.0 V, C_S = 0, T_J = +25°C)	t _{ds}	-	0.2	0.5	μS
Supply Current (V _{CC} = +35 V)	I _{CC}	_	14	20	mA

^{6.} Applies to SG3525A only, due to polarity of output pulses.

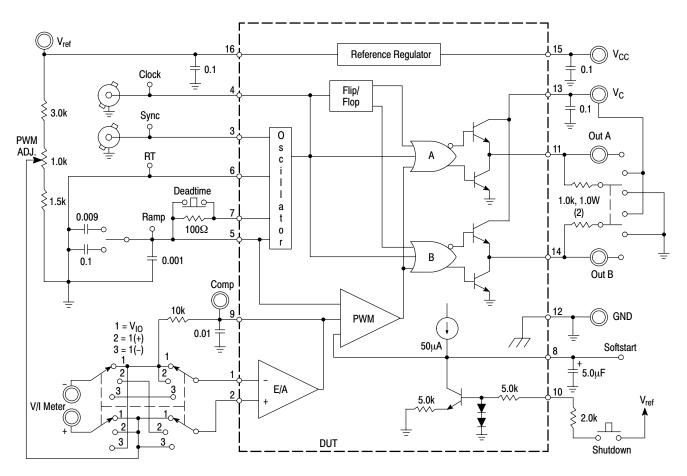


Figure 2. Lab Test Fixture

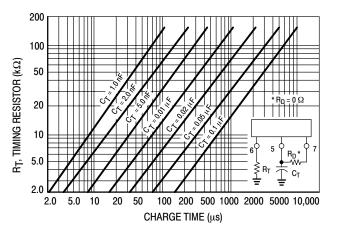


Figure 3. Oscillator Charge Time versus R_T

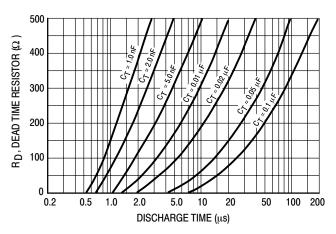


Figure 4. Oscillator Discharge Time versus R_D

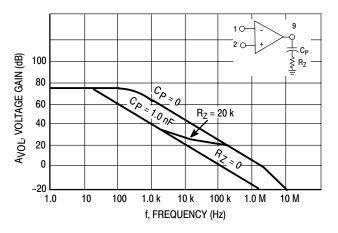


Figure 5. Error Amplifier Open Loop Frequency Response

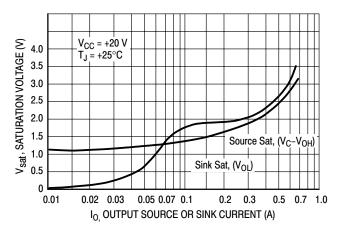


Figure 6. Output Saturation Characteristics

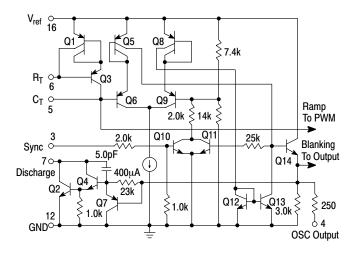


Figure 7. Oscillator Schematic

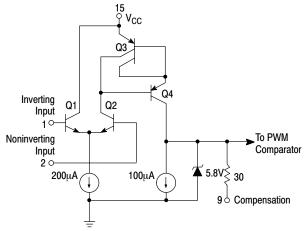


Figure 8. Error Amplifier Schematic

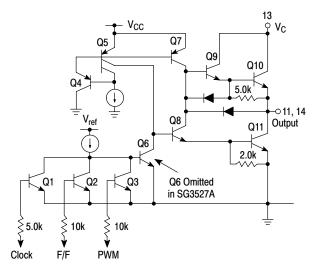
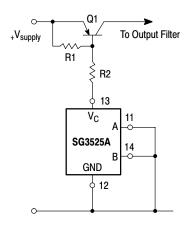
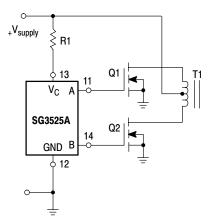


Figure 9. Output Circuit (1/2 Circuit Shown)



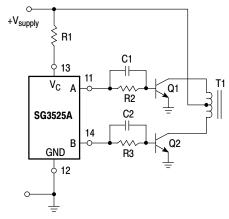
For single–ended supplies, the driver outputs are grounded. The V_C terminal is switched to ground by the totem–pole source transistors on alternate oscillator cycles.

Figure 10. Single-Ended Supply



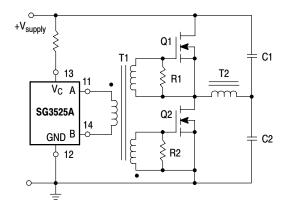
The low source impedance of the output drivers provides rapid charging of power FET input capacitance while minimizing external components.

Figure 12. Driving Power FETS



In conventional push–pull bipolar designs, forward base drive is controlled by R1–R3. Rapid turn–off times for the power devices are achieved with speed–up capacitors C1 and C2.

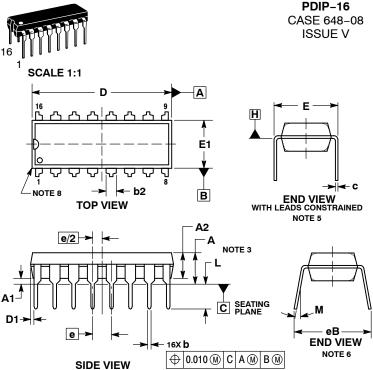
Figure 11. Push-Pull Configuration



Low power transformers can be driven directly by the SG3525A. Automatic reset occurs during deadtime, when both ends of the primary winding are switched to ground.

Figure 13. Driving Transformers in a Half-Bridge Configuration

MECHANICAL CASE OUTLINE



PDIP-16

DATE 22 APR 2015

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

- DIMENSIONING AND TOLERANGING FER ASME 114-3M, 1994
 CONTROLLING DIMENSION: INCHES.

 DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACKAGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3.

 DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH
 OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS ARE
 NOT TO EXCEED 0.10 INCH.
- DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR
- DIMENSION eB IS MEASURED AT THE LEAD TIPS WITH THE
- DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE
- LEADS, WHERE THE LEADS EXIT THE BODY.

 PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CORNERS).

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α		0.210		5.33
A1	0.015		0.38	
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060	TYP	1.52	TYP
С	0.008	0.014	0.20	0.36
D	0.735	0.775	18.67	19.69
D1	0.005		0.13	
E	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
е	0.100	BSC	2.54 BSC	
eB		0.430		10.92
L	0.115	0.150	2.92	3.81
M		10°		10°

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code

= Assembly Location

WL = Wafer Lot YY = Year

WW = Work Week

G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 1	:	STYLE 2	:
PIN 1.	CATHODE	PIN 1.	COMMON DRAIN
2.	CATHODE	2.	COMMON DRAIN
3.	CATHODE	3.	COMMON DRAIN
4.	CATHODE	4.	COMMON DRAIN
5.	CATHODE	5.	COMMON DRAIN
6.	CATHODE	6.	COMMON DRAIN
7.	CATHODE	7.	COMMON DRAIN
8.	CATHODE	8.	COMMON DRAIN
9.	ANODE	9.	GATE
10.	ANODE	10.	SOURCE
11.	ANODE	11.	GATE
12.	ANODE	12.	SOURCE
13.	ANODE	13.	GATE
14.	ANODE	14.	SOURCE
15.	ANODE	15.	GATE
16.	ANODE	16.	SOURCE

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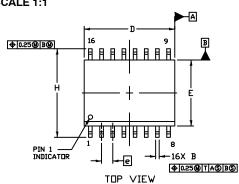


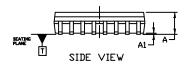


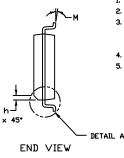
SOIC-16 WB CASE 751G ISSUE E

DATE 08 OCT 2021









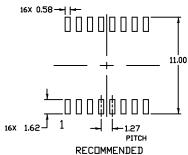


DETAIL A

NOTES

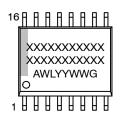
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS
- DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
- MAXIMUM MOLD PROTRUSION OR FLASH TO BE 0.15 PER SIDE.

	MILLIMETERS		
DIM	MIN.	MAX.	
Α	2.35	2.65	
A1	0.10	0.25	
В	0.35	0.49	
С	0.23	0.32	
D	10.15	10.45	
E	7.40	7.60	
е	1.27	BSC	
Н	10.05	10.55	
h	0.53 REF		
١	0.50	0.90	
М	0*	7*	



MOUNTING FOOTPRINT

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location

WL = Wafer Lot YY = Year ww = Work Week = Pb-Free Package

not follow the Generic Marking.

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may

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